

Antiferromagnetic order and magnetoelectricity of charge carriers in quantum wells

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Outline

- Introduction & Motivation
 - basics of the magnetolectric effect
 - quasi-2D/quantum well structures
- Magnetoelectricity in quasi-2D itinerant-electron para-, ferro-, and antiferromagnets
- Antiferromagnetic order of charge carriers
 - new quantity $\langle \tau \rangle$: AFM analog of spin polarisation $\langle \sigma \rangle$
- multi-band $\mathbf{k} \cdot \mathbf{p}$ model for diamond AFM
- Conclusions

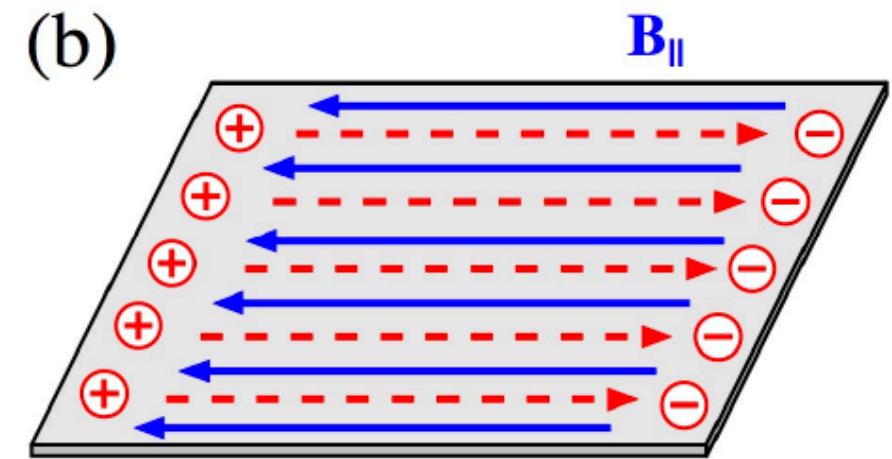
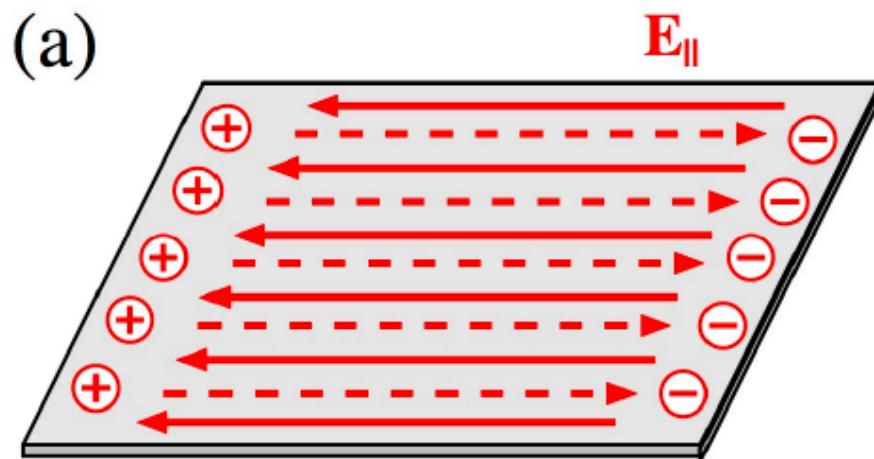
Introduction: Magnetolectric effect

Magnetoelectric effect

- magnetoelectric media: unusual electromagnetic response O'Dell, *The Electrodynamics of Magneto-electric Media* (1970)

$$\mathcal{P} = \epsilon_0 \underline{\chi}_{\mathcal{E}} \cdot \mathcal{E} + \underline{\alpha} \cdot \mathcal{B}$$

$$\mathcal{M} = \mu_0 \underline{\alpha}^T \cdot \mathcal{E} + \mu_0^{-1} \underline{\chi}_{\mathcal{B}} \cdot \mathcal{B}$$

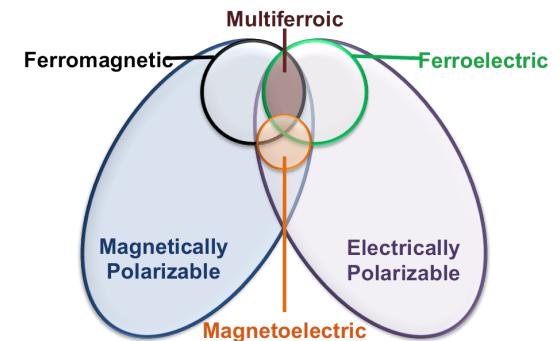


Magnetoelectric effect

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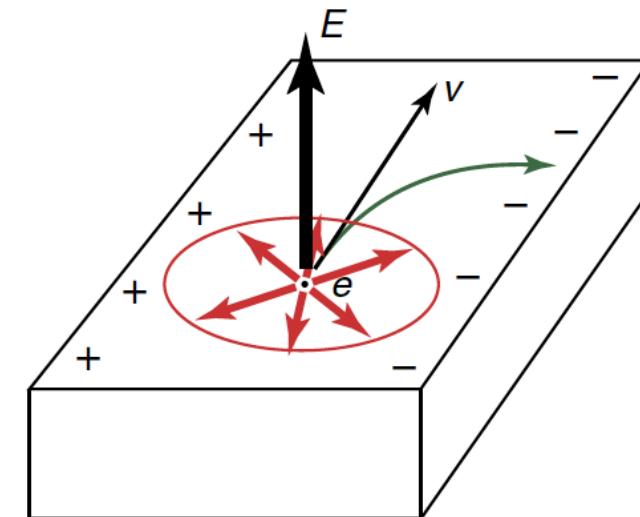
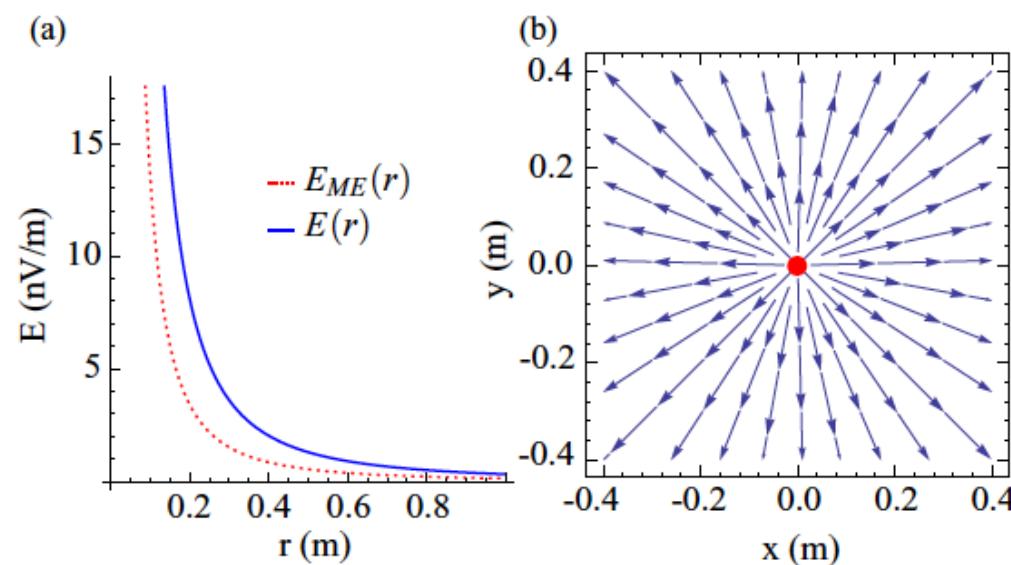


- magnetoelectric tensor: $\alpha_{ij} = a \delta_{ij} + \tilde{\tau}_k \varepsilon_{ijk} + q_{ij}$
 - can be separated into the sum of a uniform (axion) part, a toroidal part, and a quadrupolar part
 - requires broken inversion and time-reversal symmetry
 - typically in complex materials: multiferroics Fiebig et al, Nat Rev Mat (2016), topological insulators Qi & Zhang, PRB (2008)

Unusual electromagnetism in magnetoelectrics

- electromagnetism turned on its head/**perfectly dual!**
Fechner et al., PRB (2014); Khomskii, Nat Comms (2014)
 - electric charge generates **magnetic-monopole field**
 - thus **magnetic fields** accelerate an electric charge
 - electric Hall effect, magneto-photovoltaic effect, ...

Fechner et al., PRB **89**, 184415 (2014)



Khomskii, Nat Comms **5**, 4793 (2014)

Questions

- Magnetoelectricity in more ordinary materials?
 - especially in (low-D) conductors \Rightarrow spintronics!
 - equilibrium magnetoelectric responses \Rightarrow alternative to dissipative Edelstein effect!
- How can magnetoelectricity be manipulated?
 - multiferroics: only tuneable by temperature!
 - topological insulators: quantized!
- Can we obtain a unified microscopic description for both of the dual magnetoelectric responses?
 - most works focused either on magnetically induced polarisation or electrically induced magnetisation!

Introduction: Quantum wells realised in semiconductor heterostructures

Quantum wells: Quasi-2D electron systems

- band-gap engineering in semiconductor heterostructures realises **tunable quantum-well potential**
 - perpendicular electric field shifts quasi-2D bound state
 - magnetoelectricity:** in-plane magnetic field does same!

Image credit: Roland Winkler

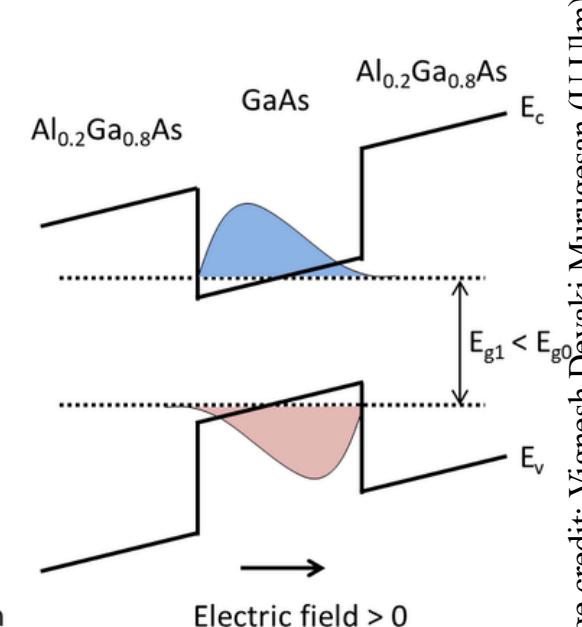
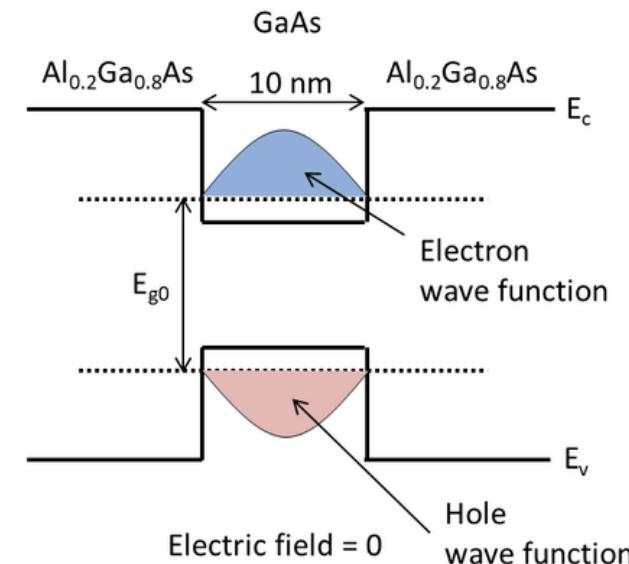
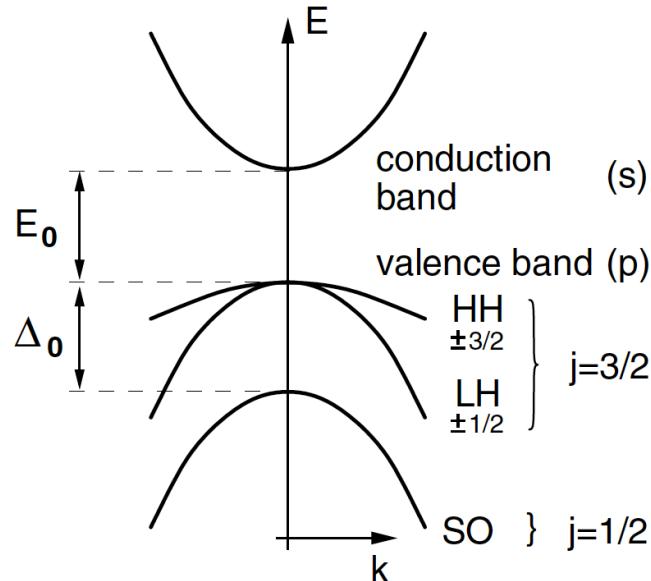
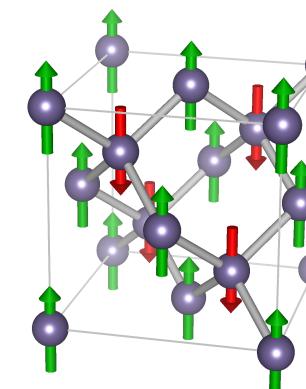
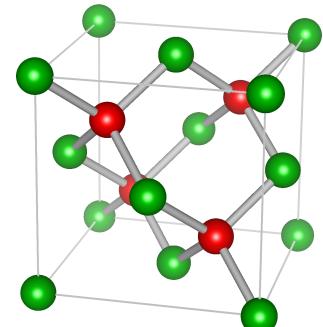
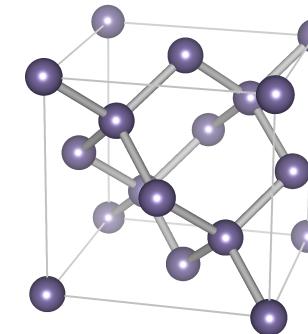


Image credit: Vignesh Devakumar Murugesan (U Ulm)

Bulk materials: Variants of diamond structure

- diamond structure: Si, Ge, ...
 - inversion & time-reversal symmetric
 - **not magnetoelectric**
- zincblende structure: GaAs, InSb, ...
 - broken inversion/intact time-reversal symmetry
 - **becomes magnetoelectric when magnetised**
- diamond antiferromagnet: CoRh_2O_4
 - broken inversion & time-reversal symmetry
 - combined inversion*time-reversal symmetric
 - **has all ingredients for magnetoelectricity**



Electric/magnetic responses in 2D systems

- solve Schrödinger equation with
 - symmetric confining potential $V(z)$
 - electric potential $e\mathcal{E}_z z$
 - vector potential $\mathcal{A} = z \mathcal{B}_{||} \times \hat{\mathbf{z}}$
- obtain eigenstates $\Psi_{n\mathbf{k}_{||}}(\mathbf{r}) = \frac{e^{i\mathbf{k}_{||}\cdot\mathbf{r}}}{2\pi} \Phi_{n\mathbf{k}_{||}}(z)$
 - subband index n
 - in-plane wave vector $\mathbf{k}_{||}$
- perp. **polarisation**: $\mathcal{P}_z = -\frac{e}{w} \sum_n \int \frac{d^2 k_{||}}{(2\pi)^2} f(E_{n\mathbf{k}_{||}}) \langle z \rangle_{n\mathbf{k}_{||}}$
- in-plane **magnetisation**:

$$\mathcal{M}_{||} = -\frac{e}{w} \sum_n \int \frac{d^2 k_{||}}{(2\pi)^2} f(E_{n\mathbf{k}_{||}}) \hat{\mathbf{z}} \times \langle \{z, \mathbf{v}_{||}\} \rangle_{n\mathbf{k}_{||}}$$

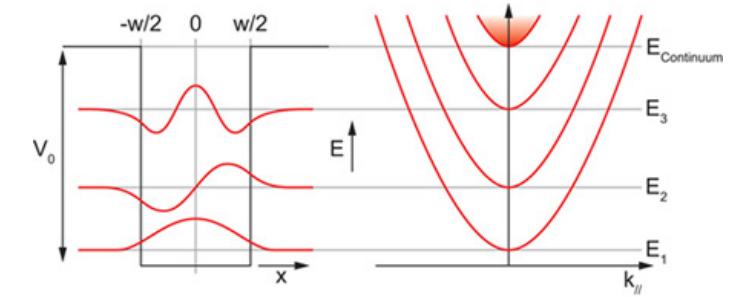


Image credit: Paul Townsend

Analytical model for the conduction band

FM quantum well

$$\mathsf{H} = \mathsf{H}_k + V(z) + \mathsf{H}_{\mathcal{D}} + \mathsf{H}_{\mathcal{Z}} + e\mathcal{E}_z z$$

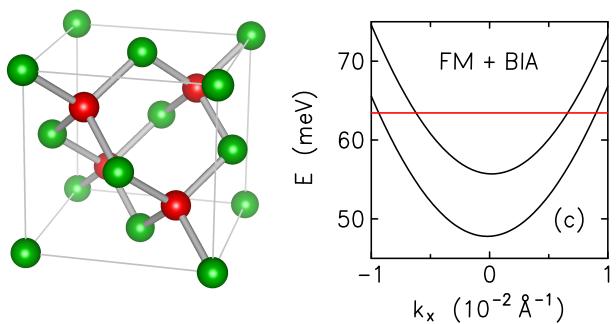
$$\mathsf{H}_k = \frac{\hbar^2 k^2}{2m}$$

$$\mathsf{H}_{\mathcal{D}} = d \left(\{k_x, k_y^2 - k_z^2\} \sigma_x + \text{c.p.} \right)$$

$$\mathsf{H}_{\mathcal{Z}} = \mathcal{Z} \cdot \boldsymbol{\sigma} \quad \mathcal{Z} \dots \text{Zeeman/exchange field}$$

$$\mathsf{H} = \frac{\hbar^2 k_z^2}{2m} + V(z) + \frac{\hbar^2}{2m} (\mathbf{k}_{||} - \mathbf{k}_0)^2 - \frac{\hbar^2 k_0^2}{2m} + \mathcal{Z} \sigma_z + e\mathcal{E}_z z$$

$$\mathbf{k}_0 = \frac{m}{\hbar^2} d k_z^2 \left[\begin{pmatrix} \cos \varphi_{\mathcal{Z}} \\ -\sin \varphi_{\mathcal{Z}} \end{pmatrix} \sigma_z - \begin{pmatrix} \sin \varphi_{\mathcal{Z}} \\ \cos \varphi_{\mathcal{Z}} \end{pmatrix} \sigma_x \right]$$



AFM quantum well

$$\mathsf{H} = \mathsf{H}_k + V(z) + \mathsf{H}_{\mathcal{N}} + e\mathcal{E}_z z$$

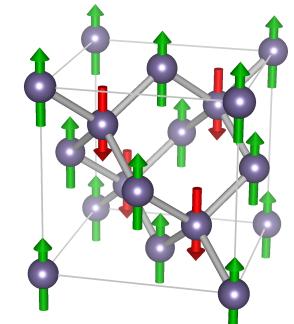
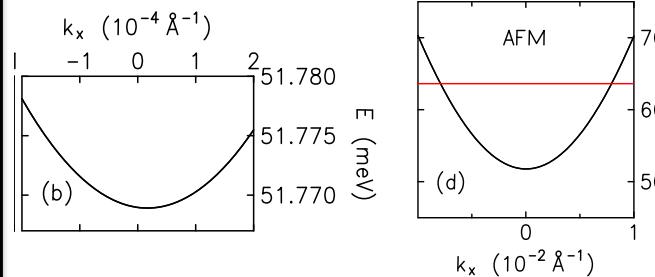
$$\mathsf{H}_k = \frac{\hbar^2 k^2}{2m}$$

$$\mathsf{H}_{\mathcal{N}} = \tilde{d} \left(\{k_x, k_y^2 - k_z^2\} \mathcal{N}_x + \text{c.p.} \right)$$

$$\mathcal{N} = \mathcal{Y}/\mathcal{Y}; \mathcal{Y} \dots \text{staggered exchange field}$$

$$\mathsf{H} = \frac{\hbar^2 k_z^2}{2m} + V(z) + \frac{\hbar^2}{2m} (\mathbf{k}_{||} - \mathbf{k}_0)^2 - \frac{\hbar^2 k_0^2}{2m} + e\mathcal{E}_z z$$

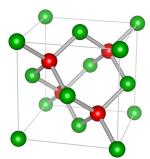
$$\mathbf{k}_0 = \frac{m}{\hbar^2} \tilde{d} k_z^2 \begin{pmatrix} \cos \varphi_{\mathcal{N}} \\ -\sin \varphi_{\mathcal{N}} \end{pmatrix}$$



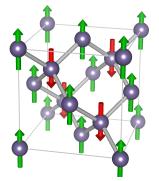
Magnetoelectric response I: Electric-field-induced in-plane magnetisation

Analytical results for conduction band

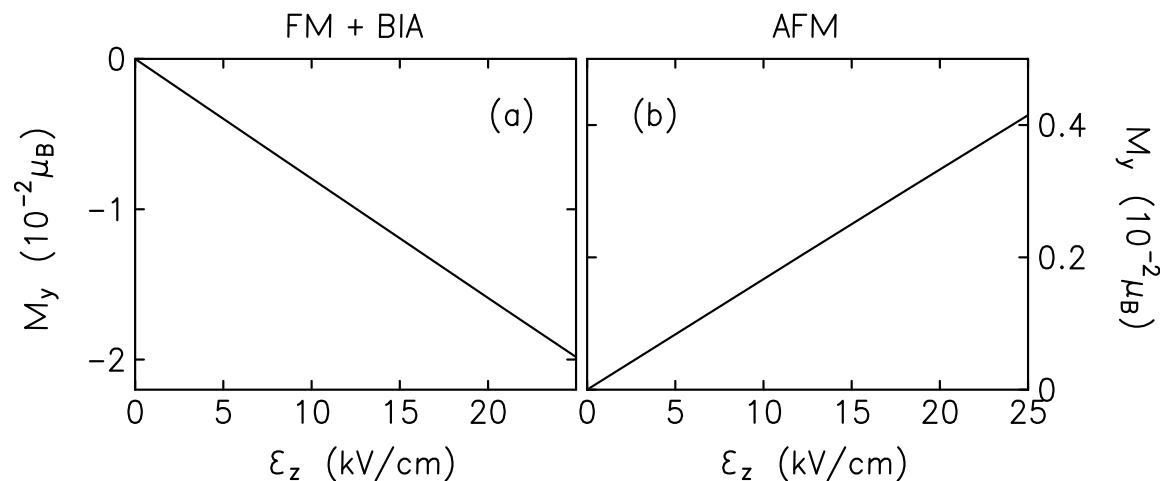
- perturbative treatment of \mathcal{E}_z yields results for the **in-plane magnetisation**:



$$\mathcal{M}_{\parallel} = \mathcal{M}_0 e \mathcal{E}_z w \lambda_d \xi(\mathcal{Z}) \begin{pmatrix} \sin \varphi_{\mathcal{Z}} \\ \cos \varphi_{\mathcal{Z}} \end{pmatrix} \quad \mathcal{M}_{\parallel} = -\mathcal{M}_0 e \mathcal{E}_z w \lambda_{\tilde{d}} \begin{pmatrix} \sin \varphi_{\mathcal{N}} \\ \cos \varphi_{\mathcal{N}} \end{pmatrix}$$

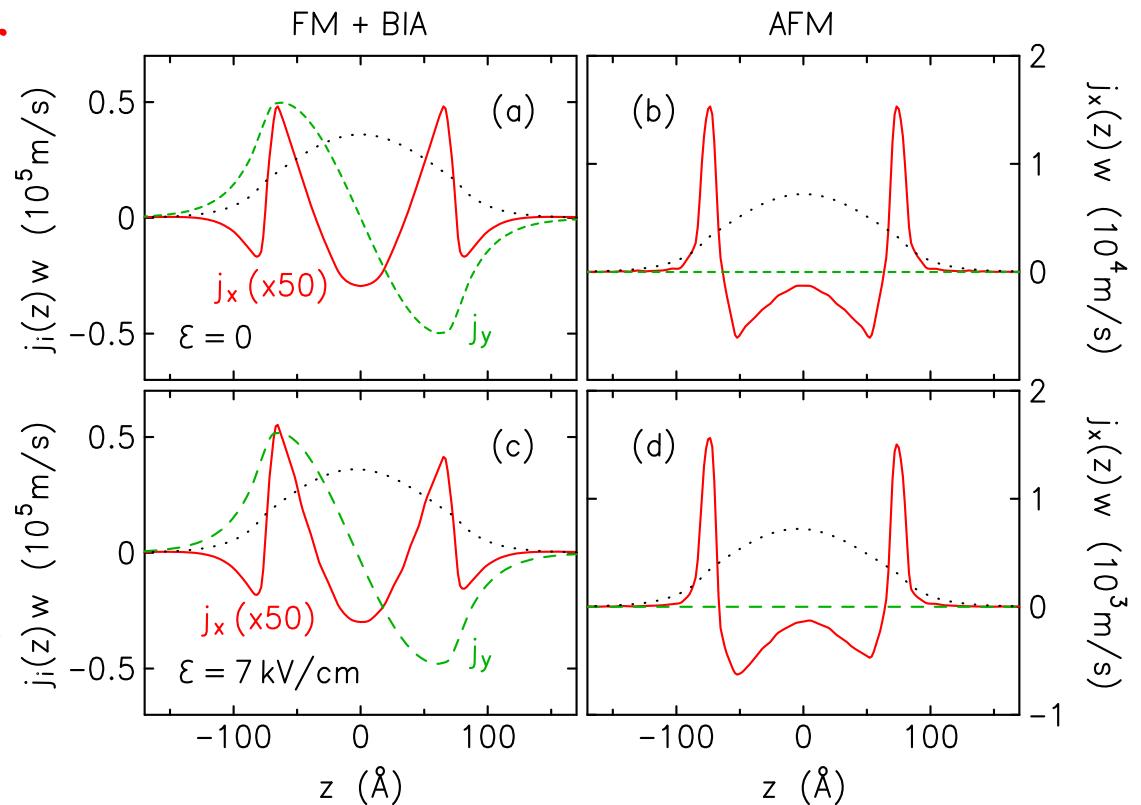


- direction determined by (staggered) exchange field
 - details of quantum-well structure enter $\lambda_d, \lambda_{\tilde{d}}$
 - overall scale:
- $$\mathcal{M}_0 = -\mu_B N_s / w$$
- small magnitude (per particle)



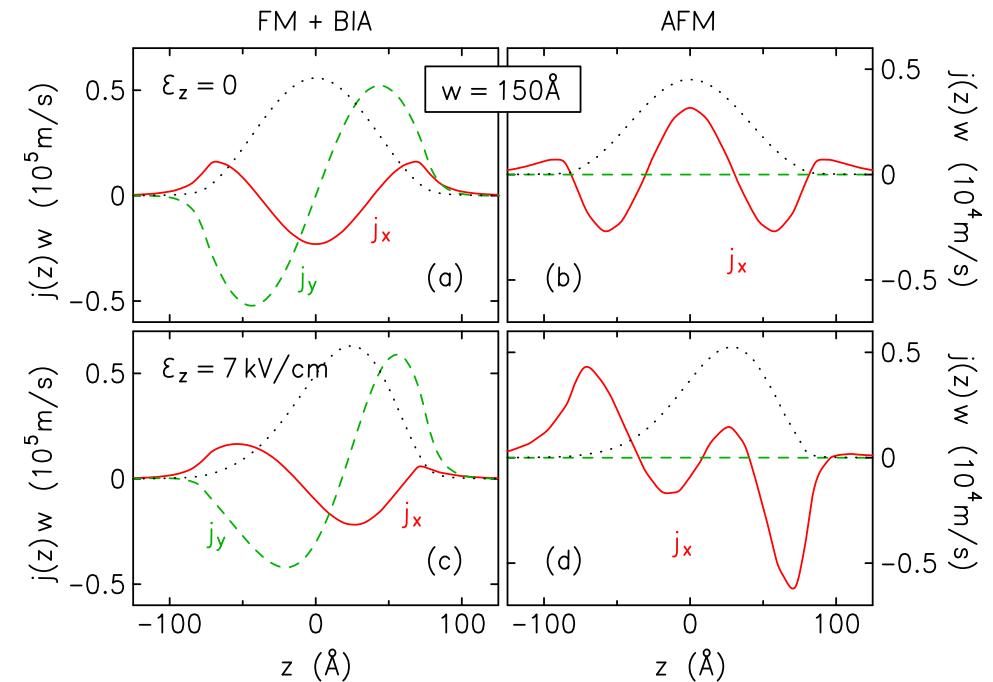
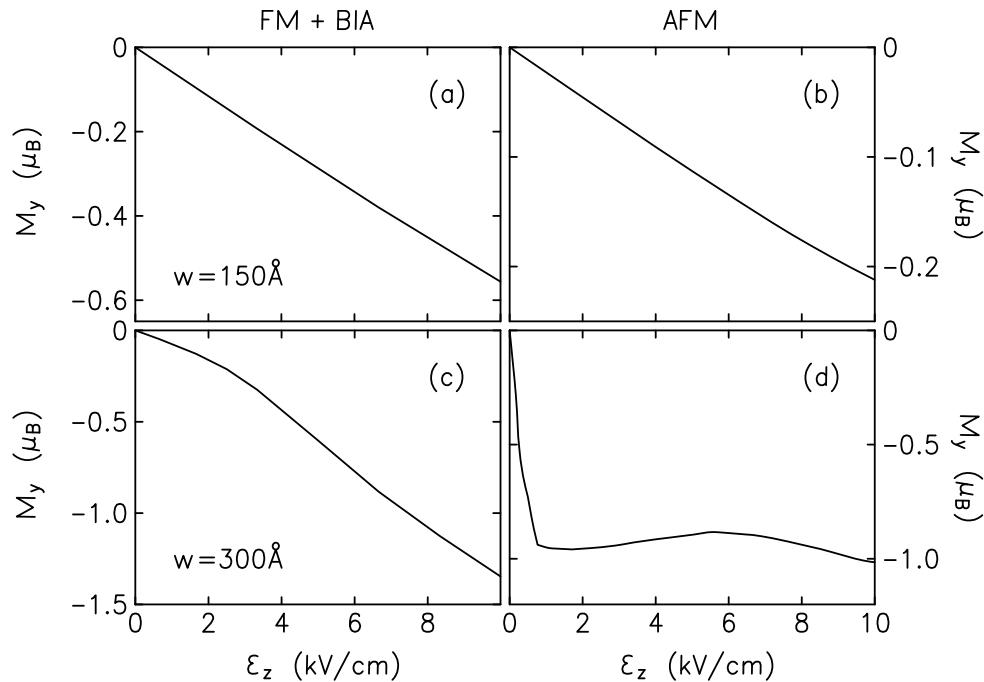
Physical picture

- electric field modifies the **equilibrium-current distribution** in quasi-2D ferro-/antiferromagnets
 - zero \mathcal{E}_z : **quadrupolar** equilibrium currents
 - finite \mathcal{E}_z distorts the quadrupolar equilib. currents, generates a **dipolar** component
 - \mathcal{E}_z -induced in-plane magnetisation!



Results for valence-band carriers (holes)

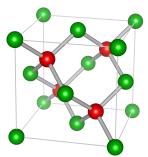
- same basic physics, but **much larger magnitude!**
 - induced magnetisation/particle reaches $\sim 1 \mu_B$
- peculiarities of **valence-band structure** relevant



Magnetoelectric response II: Magnetic-field-induced out-of-plane polarisation

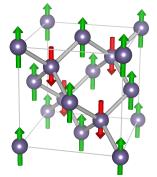
Analytical results for conduction band

- perturbative treatment of \mathcal{B}_{\parallel} yields results for the **out-of-plane electric polarisation**:

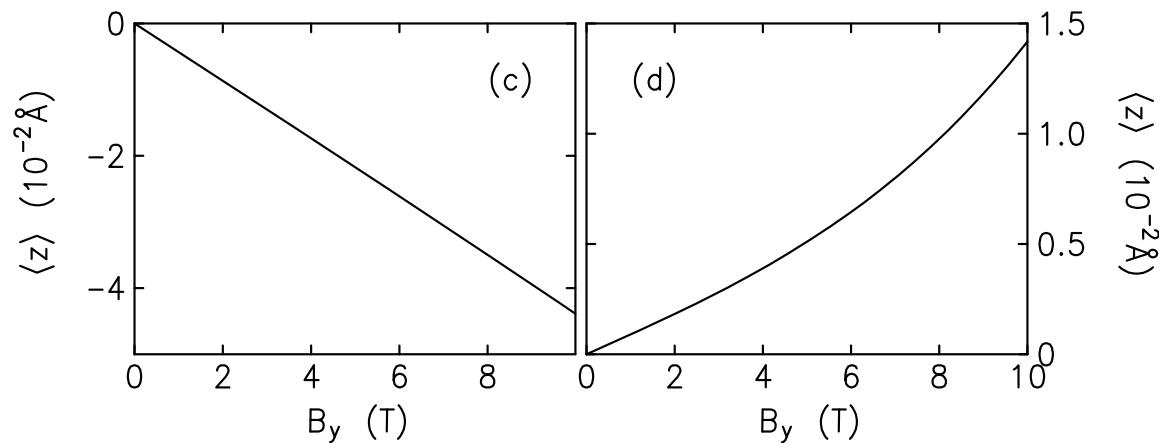


$$\mathcal{P}_z = \mathcal{P}_0 \mu_B \mathcal{B}_{\parallel} \lambda_d \xi(\mathcal{Z}) \sin(\varphi_z + \varphi_{\parallel})$$

$$\mathcal{P}_z = \mathcal{P}_0 \mu_B \mathcal{B}_{\parallel} \lambda_{\tilde{d}} \sin(\varphi_N + \varphi_{\parallel})$$

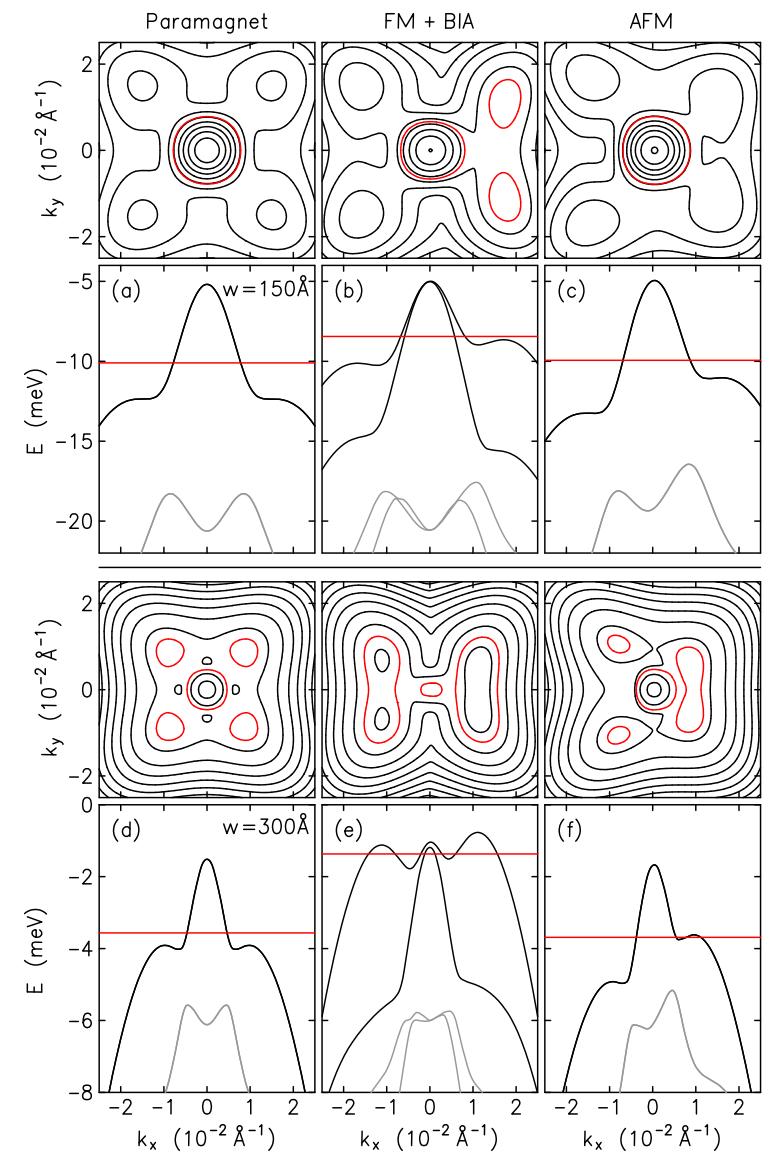
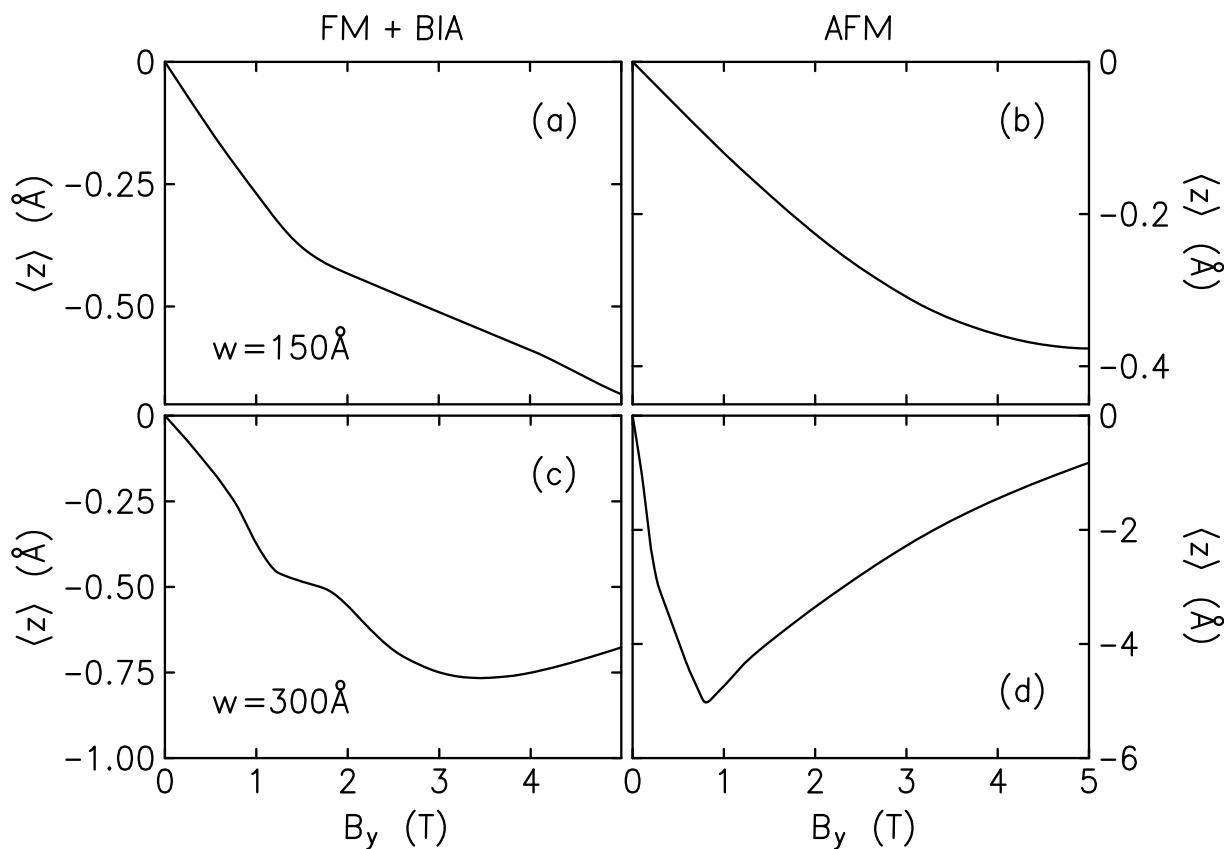


- modulated by direction of (staggered) exchange field
 - details of quantum-well structure enter $\lambda_d, \lambda_{\tilde{d}}$
 - overall scale is
- $$\mathcal{P}_0 = -eN_s$$
- typically a very small magnitude



Results for holes

- larger magnitude; complexity of subband structure matters



Antiferromagnetic order of charge carriers in ferro- and antiferromagnetic 2D systems

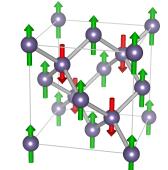
Quantifying AFM order of charge carriers

- ferromagnetism manifests in the **band structure** as an **exchange field \mathcal{X}**
 - relevant term in Hamiltonian: $H_{\mathcal{X}} = \mathcal{X} \cdot \sigma$
 - generates spin polarisation $\langle \sigma \rangle$ of the charge carriers
- antiferromagnetism is associated with **staggered exchange field \mathcal{Y}**
 - term in Hamiltonian: $H_{\mathcal{Y}} = \frac{\tilde{d}}{\mathcal{Y}} (\{k_x, k_y^2 - k_z^2\} \mathcal{Y}_x + \text{c.p.})$
 - rewrite as $H_{\mathcal{Y}} = \mathcal{Y} \cdot \tau$
 - quantity $\langle \tau \rangle$ represents **antiferromagnetic order of the charge carriers** generally, not only in antiferromagnets!

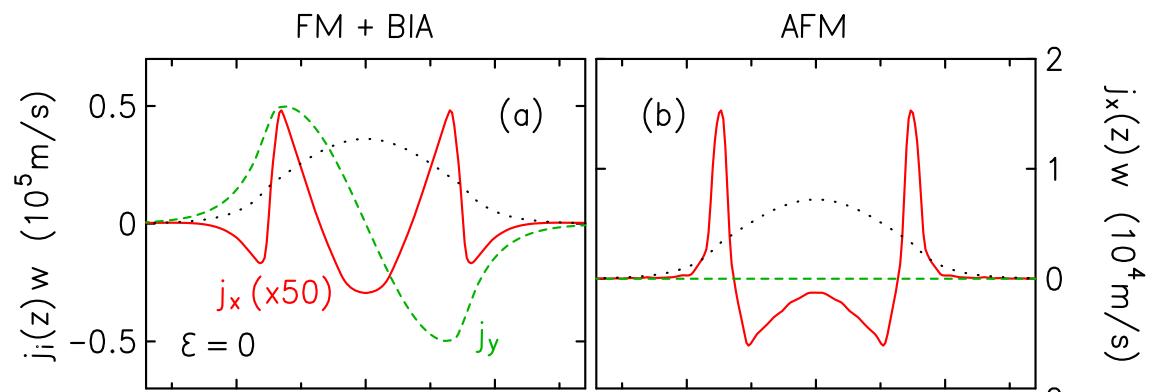
Antiferromagnetic order in quantum wells

- for conduction-band electrons: $\tau = q_\tau k_z^2 \begin{pmatrix} k_x \\ -k_y \end{pmatrix}$
 - results for quantum wells:

$$\langle \tau \rangle = 2\pi q_\tau d N_s \xi(\mathcal{Z}) \begin{pmatrix} \cos \varphi_{\mathcal{Z}} \\ \sin \varphi_{\mathcal{Z}} \end{pmatrix} \sum_{\nu' \neq 0} \frac{|\langle \nu' | k_z^2 | 0 \rangle|^2}{E_{\nu'}^{(0)} - E_0^{(0)}} \quad \langle \tau \rangle = 2\pi q_\tau \tilde{d} N_s \begin{pmatrix} \cos \varphi_{\mathcal{N}} \\ \sin \varphi_{\mathcal{N}} \end{pmatrix} \sum_{\nu' \neq 0} \frac{|\langle \nu' | k_z^2 | 0 \rangle|^2}{E_{\nu'}^{(0)} - E_0^{(0)}}$$



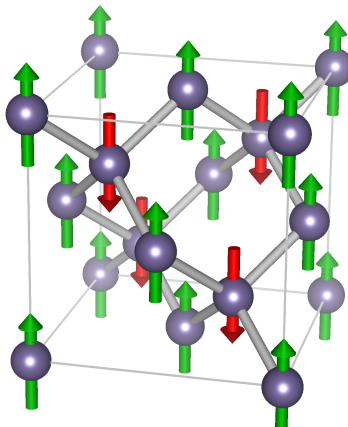
- vector $\langle \tau \rangle$ is parallel to (staggered) exchange field
 - collinear antiferromagnetic order of charge carriers measured by $\langle \tau \rangle$
 - reflects quadrupolar equilibrium currents



Envelope-function theory for charge carriers in diamond antiferromagnets

Band structure of diamond antiferromagnet

- tight-binding model for diamond, resp. zincblende structures + staggered exchange field \mathcal{Y}
- obtain 14×14 extended Kane model description for the band structure
- additional terms involving \mathcal{Y}



$$\begin{aligned}
 \mathcal{H}_{8c\ 8v}^y &= (2i/3) \mathcal{Y} (\mathcal{N}_x J_x + \text{cp}) \\
 \mathcal{H}_{8c\ 7v}^y &= -2i \mathcal{Y} (\mathcal{N}_x U_x + \text{cp}) \\
 \mathcal{H}_{7c\ 7v}^y &= (-i/3) \mathcal{Y} (\mathcal{N}_x \sigma_x + \text{cp}) \\
 \mathcal{H}_{6c\ 6c}^y &= d(\{\mathcal{k}_x, \mathcal{k}_y^2 - k_z^2\} \mathcal{N}_x + \text{cp}) \\
 \mathcal{H}_{8v\ 8v}^y &= \mathcal{D}_{88}^1(\{\mathcal{k}_x, \mathcal{k}_y^2 - k_z^2\} \mathcal{N}_x + \text{cp}) \\
 &\quad + \mathcal{D}_{88}^2[(\mathcal{N}_y \mathcal{k}_y - \mathcal{N}_z \mathcal{k}_z) J_x^2 + \text{cp}] \\
 &\quad + \mathcal{D}_{88}^3[(\mathcal{N}_x \mathcal{k}_y - \mathcal{N}_y \mathcal{k}_x) \{J_x, J_y\} + \text{cp}] \\
 &\quad + \mathcal{D}_{88}^4[(\mathcal{N}_y \mathcal{E}_z - \mathcal{N}_z \mathcal{E}_y) \{J_x, J_y^2 - J_z^2\} + \text{cp}] \\
 &\quad + \mathcal{D}_{88}^5[(\mathcal{N}_y \mathcal{E}_z + \mathcal{N}_z \mathcal{E}_y) J_x + \text{cp}] \\
 &\quad + \mathcal{D}_{88}^6[(\mathcal{N}_y \mathcal{E}_z + \mathcal{N}_z \mathcal{E}_y) J_x^3 + \text{cp}] \\
 &\quad + \mathcal{D}_{88}^7(\mathcal{N}_x \mathcal{E}_x + \text{cp})(J_x J_y J_z + J_z J_y J_x) \\
 \mathcal{H}_{7v\ 7v}^y &= \mathcal{D}_{77}^1(\{\mathcal{k}_x, \mathcal{k}_y^2 - k_z^2\} \mathcal{N}_x + \text{cp})
 \end{aligned}$$

$\mathcal{N} = \mathcal{Y}/\gamma$

Conclusions

- studied equilibrium magnetoelectric effects for charge carriers in quasi-2D systems
 - interplay of ferro-/antiferromagnetic exchange fields, quantum confinement, inversion-asymmetric bulk
 - sizable, tuneable, microscopically describable
- derived envelope-function theory for diamond-antiferromagnet bands (generalised Kane model)
 - widely applicable to study AFMs' electronic properties
- derived quantity $\langle \tau \rangle$ that represents AFM order of charge carriers: analog of $\langle \sigma \rangle$ that's finite in FMs!



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